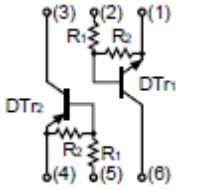
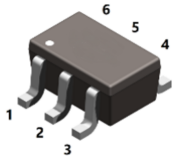
UMD34N

Dual Digital Transistor(NPN+PNP)

Features

- Both the NPN and PNP in SOT-363 package
- Built-in biasing resistors (R_1: 1kΩ, R_2: 1kΩ)
- Reduces board space
- Reduces component count
- Surface mount package suited for automated assembly





SOT-363

Mechanical Data

- Case: SOT-363
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
UMD34N	SOT-363	3000 pcs / Tape & Reel	D34

Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Symbol	Parameter	Value		Unit
		DT_{r1}	DT_{r2}	
V_{CC}	Supply Voltage	50	-50	V
V_{IN}	Input Voltage	-10 to +10	+10 to -10	V
I_O	Output Current	100	-100	mA
$I_{C\ (Max.)}$	Collector Current	100	-100	mA

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation	P_D	150	mW
Operating Junction Temperature Range	T_J	-55 ~ +150	°C
Storage Temperature Range	T_{STG}	-55 ~ +150	°C

Electrical Characteristics-DT$_{r1}$ (@ T_A = 25℃ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Input Voltage	$V_{I(OFF)}$	V_{CC} = 5V, I_O = 100μA	0.5	-	-	V
Input Voltage	$V_{I(ON)}$	V_O = 0.2V, I_O = 20mA	-	-	3	V
Output Voltage	$V_{O(on)}$	I_C = 10mA, I_B = 5mA	-	-	0.3	V
Input Current	I_I	V_I = 6V	-	-	4.3	mA
Output Current	$I_{O(off)}$	V_{CC} = 50V, V_I = 0V	-	-	0.5	μA
DC Current Gain	G_I	V_O = 10V, I_O = 5mA	3	-	-	-
Input Resistor	R_1		0.7	1.0	1.3	kΩ
Resistance ratio	R_2/R_1		0.8	1.0	1.2	-
Gain-Bandwidth Product	f_T	V_{CE} = 10V, I_E = 5mA f = 100MHz	-	250	-	MHz

Electrical Characteristics-DT$_{r2}$ (@ T_A = 25℃ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Input Voltage	$V_{I(OFF)}$	V_{CC} = -5V, I_O = -100μA	-0.5	-	-	V
Input Voltage	$V_{I(ON)}$	V_O = -0.2V, I_O = -20mA	-	-	-3	V
Output Voltage	$V_{O(on)}$	I_C = -10mA, I_B = -5mA	-	-	-0.3	V
Input Current	I_I	V_I = -6V	-	-	-4.3	mA
Output Current	$I_{O(off)}$	V_{CC} = -50V, V_I = 0V	-	-	-0.5	μA
DC Current Gain	G_I	V_O = -10V, I_O = -5mA	3	-	-	-
Input Resistor	R_1		0.7	1.0	1.3	kΩ
Resistance ratio	R_2/R_1		0.8	1.0	1.2	-
Gain-Bandwidth Product	f_T	V_{CE} = -10V, I_E = -5mA f = 100MHz	-	250	-	MHz

Ratings and Characteristics Curves-DT$_{r1}$ (@ T_A = 25°C unless otherwise specified)

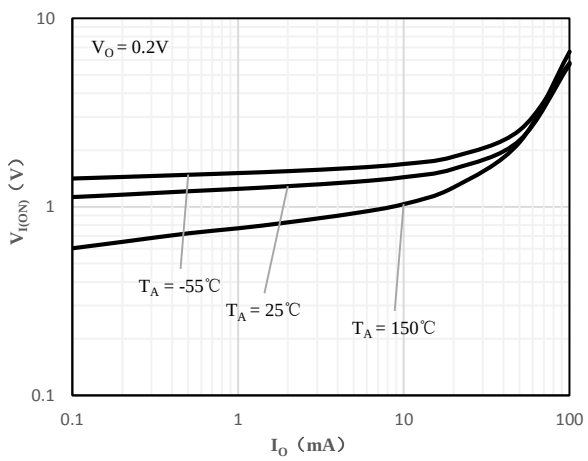


Fig 1 Input Voltage vs Output Current

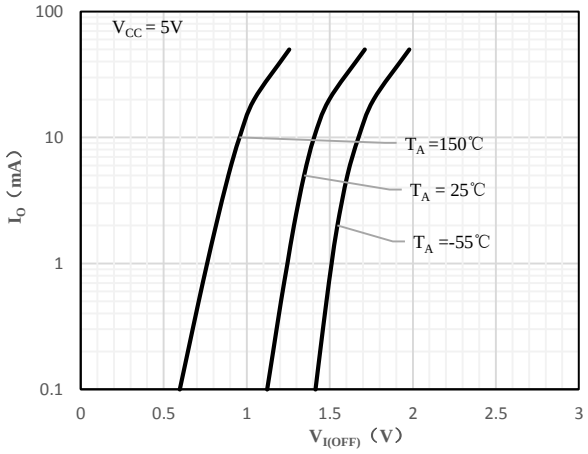


Fig 2 Output Current vs Input Voltage

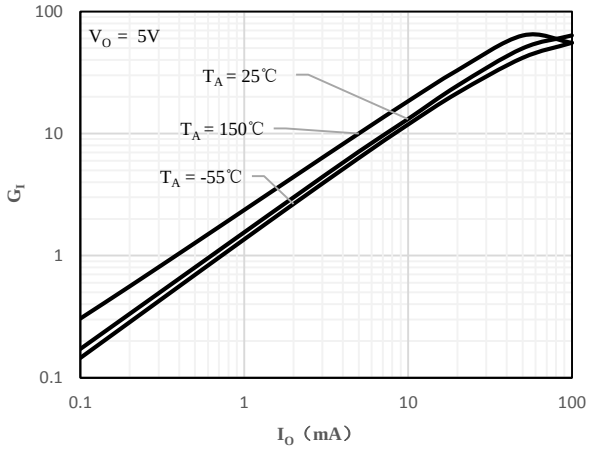


Fig 3 DC Current Gain vs Output Current

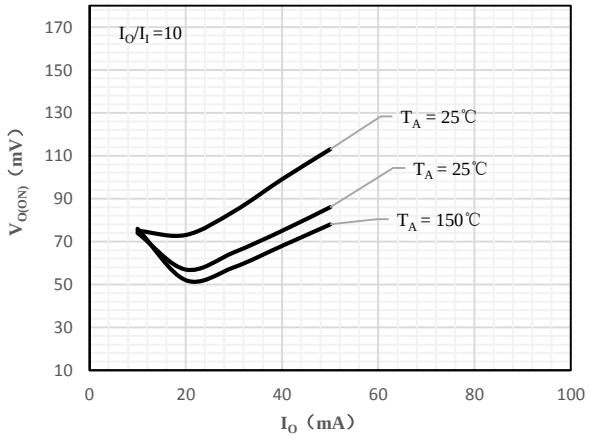


Fig 4 Output Voltage vs Output Current

Ratings and Characteristics Curves-DT$_{r2}$ (@ T_A = 25°C unless otherwise specified)

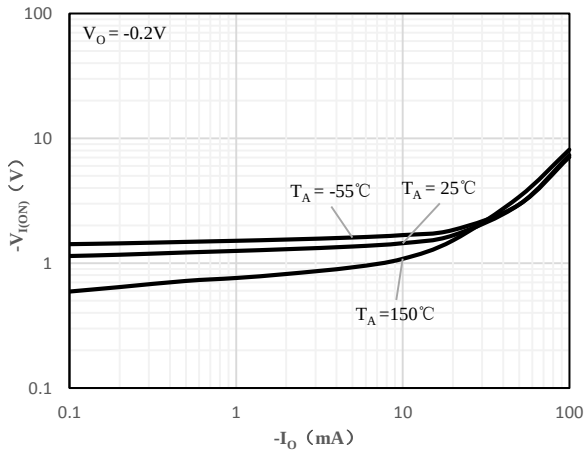


Fig 1 Input Voltage vs Output Current

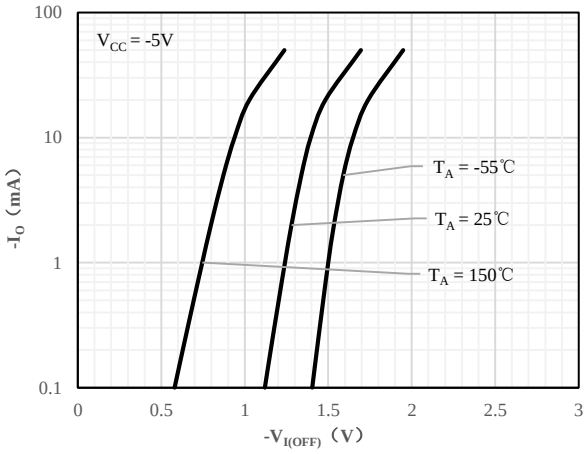


Fig 2 Output Current vs Input Voltage

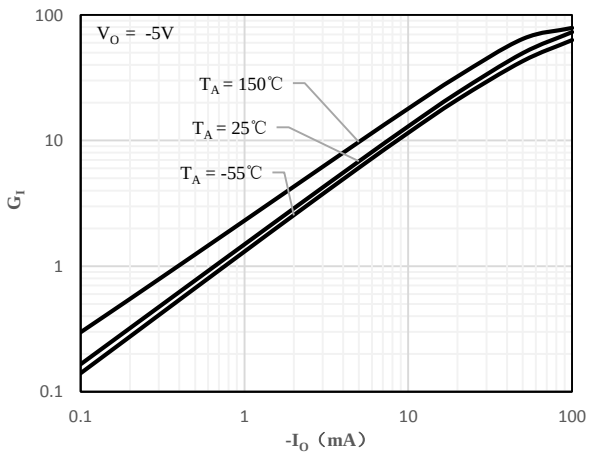


Fig 3 DC Current Gain vs Output Current

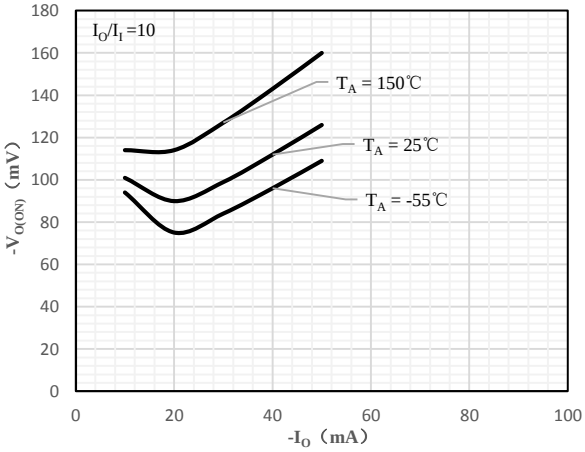
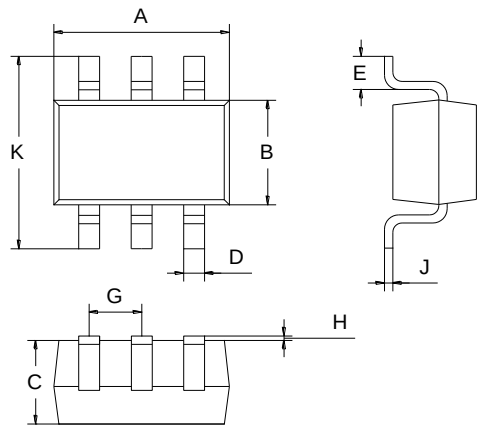


Fig 4 Output Voltage vs Output Current

Package Outline Dimensions (Unit: mm)



SOT-363		
Dimension	**Min.**	**Max.**
A	2.00	2.20
B	1.15	1.35
C	0.85	1.05
D	0.15	0.35
E	0.25	0.40
G	0.60	0.70
H	0.02	0.10
J	0.05	0.15
K	2.20	2.40

Package Outline Dimensions (Unit: mm)

SOT-363